IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In repatent application of

Masaki Hashimura, et al.

Serial No.:

Not Yet Assigned

Group Art Unit:

Not Yet Assigned

Filing Date:

Concurrently Herewith

Examiner:

Unknown

For:

SEMICONDUCTOR ELEMENT AND METHOD FOR PRODUCING THE

SAME

Honorable Commissioner of Patents Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Sir:

Prior to examination on the merits and calculation of the filing fee, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend the claims as follows:

27. (Amended) A semiconductor element according to claim 25, wherein said outer circumferential negative electrode is formed to have a height at least equal to a height of a light-emitting layer on a side of at least one side wall of said light-emitting layer.

Please add a new claim as follows:

--29. (New) A semiconductor element according to claim 26, wherein said outer circumferential negative electrode is formed to have a height at least equal to a height of a light-emitting layer on a side of at least one side wall of said light-emitting layer.--